

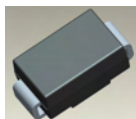
1.0A SURFACE MOUNT ULTRA-FAST RECTIFIER

Features

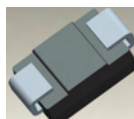
- Glass Passivated Die Construction
- Ultra-Fast Recovery Time for High Efficiency
- Surge Overload Rating to 30A Peak
- High Current Capability
- Ideally Suited for Automated Assembly
- **Lead Free Finish/RoHS Compliant (Note 1)**
- **Green Molding Compound (No Halogen and Antimony) (Note 2)**

Mechanical Data

- Case: SMA
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Lead Free Plating (Matte Tin Finish). Solderable per MIL-STD-202, Method 208 
- Polarity: Cathode Band or Cathode Notch
- Weight: 0.064 grams (approximate)



Top View



Bottom View

Ordering Information (Note 3)

Part Number*	Case	Packaging
US1x-13-F	SMA	5000/Tape & Reel

*x = Device type, e.g. US1A-13-F.

- Notes:
1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied, see EU Directive 2002/95/EC Annex Notes.
 2. Product manufactured with Data Code 0924 (week 24, 2009) and newer are built with Green Molding Compound.
 3. For packaging details, go to our website at <http://www.diodes.com>.

Marking Information



US1x = Product type marking code, ex: US1A
 DII = Manufacturers' code marking
 YWW = Date code marking
 Y = Last digit of year (ex: 2 for 2002)
 WW = Week code (01 to 53)

Maximum Ratings @T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.
 For capacitance load, derate current by 20%.

Characteristic	Symbol	US1A	US1B	US1D	US1G	US1J	US1K	US1M	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Working Peak Reverse Voltage	V _{RWM}								
DC Blocking Voltage (Note 4)	V _R								
RMS Reverse Voltage	V _{R(RMS)}	35	70	140	280	420	560	700	V
Average Rectified Output Current @ T _T = 75°C	I _O	1.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms	I _{FSM}	30							A
Single Half Sine-Wave Superimposed on Rated Load									

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance, Junction to Terminal	R _{θJT}	30	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	US1A	US1B	US1D	US1G	US1J	US1K	US1M	Unit
Forward Voltage Drop @ I _F = 1.0A	V _{FM}	1.0			1.3	1.7			V
Peak Reverse Current @ T _A = 25°C	I _{RM}	5.0							μA
at Rated DC Blocking Voltage (Note 4) @ T _A = 100°C		100							
Reverse Recovery Time (Note 5)	t _{rr}	50				75			ns
Typical Total Capacitance (Note 6)	C _T	20				10			pF

Notes: 4. Short duration pulse test used to minimize self-heating effect.
 5. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
 6. Measured with I_F = 0.5A, I_R = 1.0A, I_{rr} = 0.25A. See figure 5.

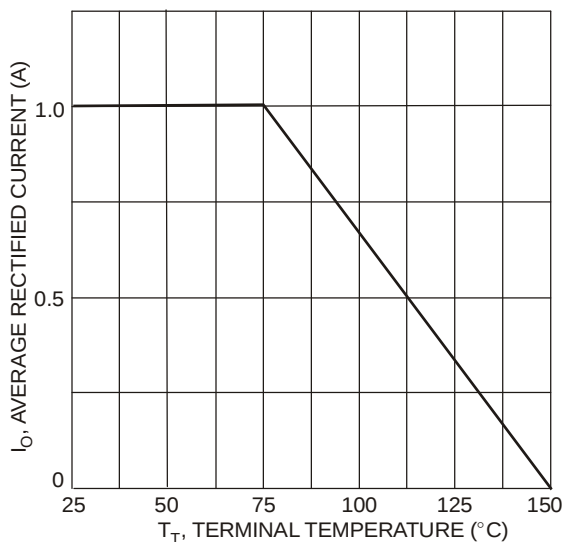


Fig. 1 Forward Current Derating Curve

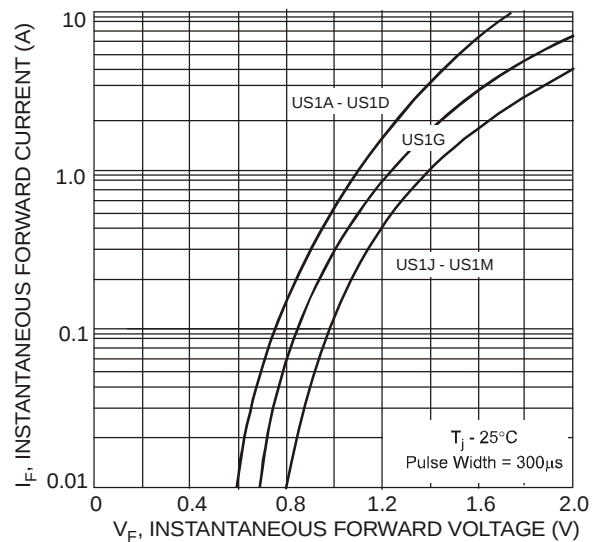


Fig. 2 Typical Forward Characteristics

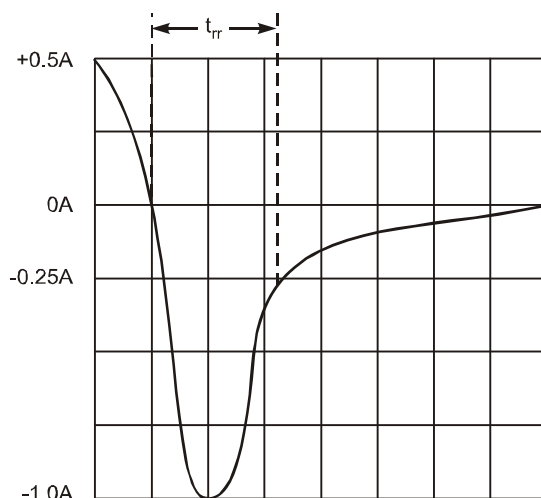
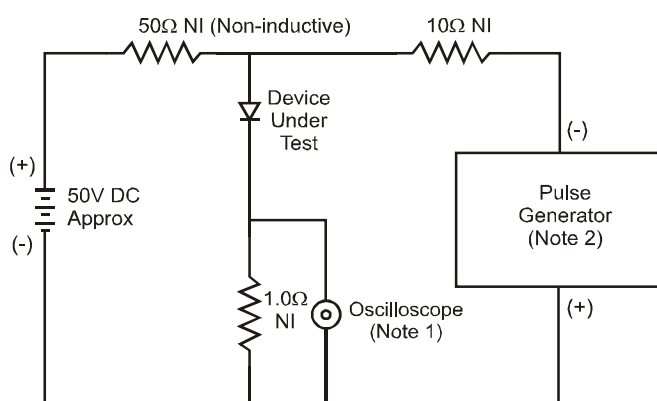
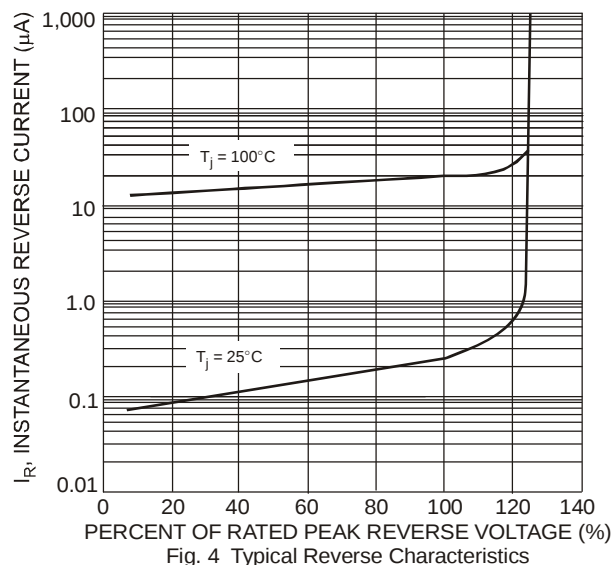
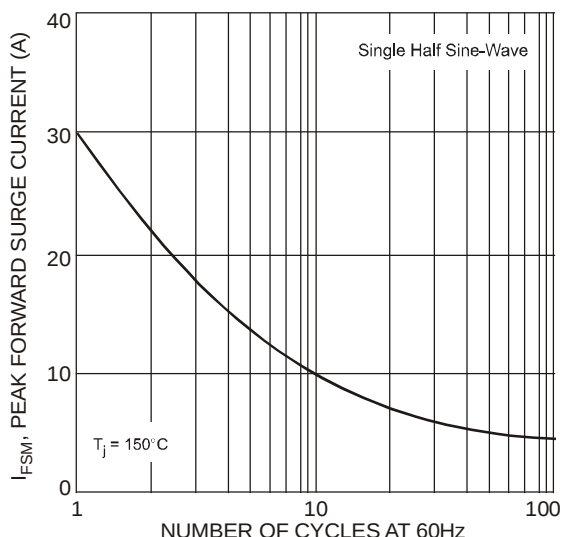
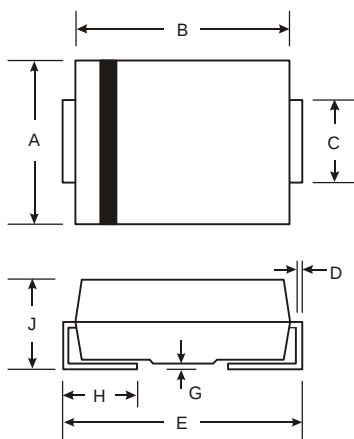


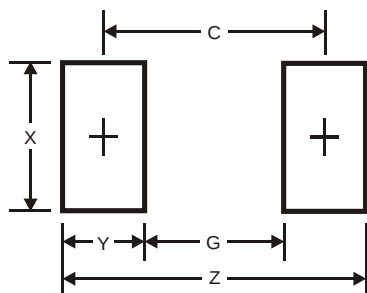
Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

Package Outline Dimensions



SMA		
Dim	Min	Max
A	2.29	2.92
B	4.00	4.60
C	1.27	1.63
D	0.15	0.31
E	4.80	5.59
G	0.05	0.20
H	0.76	1.52
J	2.01	2.30
All Dimensions in mm		

Suggested Pad Layout



Dimensions	Value (in mm)
Z	6.5
G	1.5
X	1.7
Y	2.5
C	4.0

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